

# High-voltage Switching Transistor

## (Camera strobes and Telephone, Power supply)

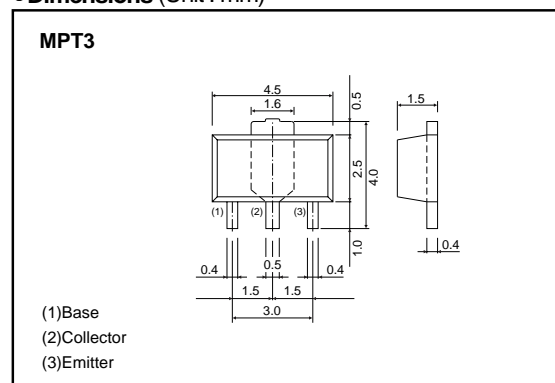
### (-400V, -0.1A)

## 2SA1759

### ●Features

- 1) High breakdown voltage. ( $BV_{CEO} = -400V$ )
- 2) Low saturation voltage,  
typically  $V_{CE(sat)} = -0.2V$  at  $I_C / I_B = -20mA / -2mA$ .
- 3) High switching speed, typically  $t_f = 1\mu s$  at  $I_C = 100mA$ .
- 4) Wide SOA (safe operating area).
- 5) Complements the 2SC4505.

### ●Dimensions (Unit : mm)



### ●Absolute maximum ratings ( $T_a = 25^\circ C$ )

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CBO}$	-400	V
Collector-emitter voltage	$V_{CEO}$	-400	V
Emitter-base voltage	$V_{EBO}$	-7	V
Collector current	$I_C$	-0.1	A(DC)
		-0.2	A(Pulse) *1
Collector power dissipation	$P_C$	0.5	W
		2 *2	
Junction temperature	$T_J$	150	$^\circ C$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ C$

\*1 Single pulse,  $P_w = 100ms$

\*2 When mounted on a  $40 \times 40 \times 0.7$  mm ceramic board.

### ●Electrical characteristics ( $T_a = 25^\circ C$ )

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CBO}$	-400	-	-	V	$I_C = -50\mu A$
Collector-emitter breakdown voltage	$BV_{CEO}$	-400	-	-	V	$I_C = -1mA$
Emitter-base breakdown voltage	$BV_{EBO}$	-7	-	-	V	$I_E = -50\mu A$
Collector cutoff current	$I_{CBO}$	-	-	-10	$\mu A$	$V_{CB} = -400V$
Emitter cutoff current	$I_{EBO}$	-	-	-10	$\mu A$	$V_{EB} = -6V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-0.2	-0.5	V	$I_C = -20mA, I_B = -2mA$
Base-emitter saturation voltage	$V_{BE(sat)}$	-	-	-1.5	V	$I_C = -20mA, I_B = -2mA$
DC current transfer ratio	$h_{FE}$	82	-	180	-	$V_{CE} = -10V, I_C = -10mA$
Transition frequency	$f_T$	-	12	-	MHz	$V_{CE} = -10V, I_E = 10mA, f = 5MHz$
Output capacitance	$C_{ob}$	-	13	-	pF	$V_{CB} = -10V, I_E = 0A, f = 1MHz$
Turn-on time	$t_{on}$	-	0.7	-	$\mu s$	$I_C = -100mA, R_L = 1.5k\Omega$
Storage time	$t_{stg}$	-	1.8	-	$\mu s$	$I_{B1} = -I_{B2} = -10mA$
Fall time	$t_f$	-	1	-	$\mu s$	$V_{CC} = -150V$

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●Packaging specifications and hFE

Type	2SA1759
Package	MPT3
hFE	P
Marking	AH*
Code	T100
Basic ordering unit (pieces)	3000

\* Denotes hFE

●Electrical characteristics (Ta=25°C)

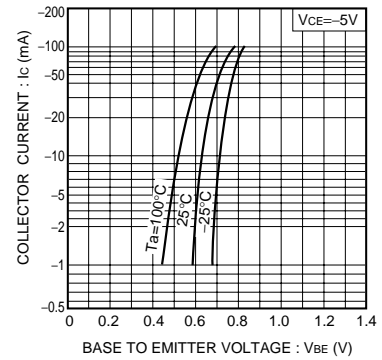
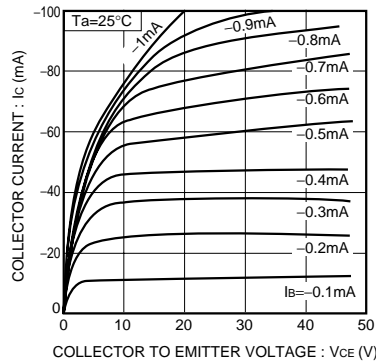
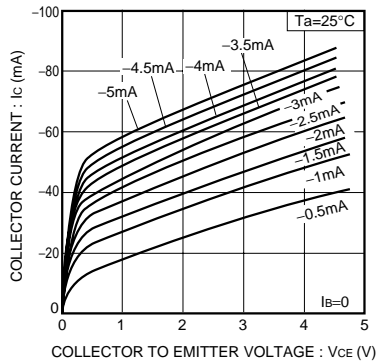


Fig.1 Ground emitter output characteristics ( I ) Fig.2 Ground emitter output characteristics ( II ) Fig.3 Ground emitter propagation characteristics

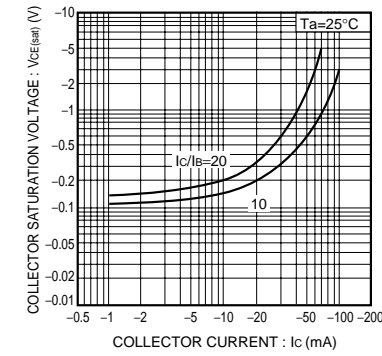
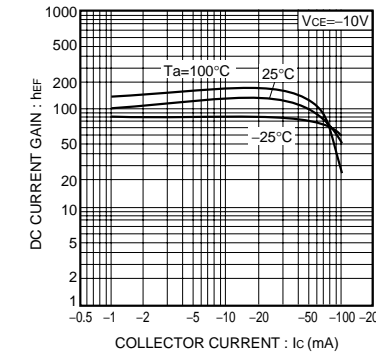
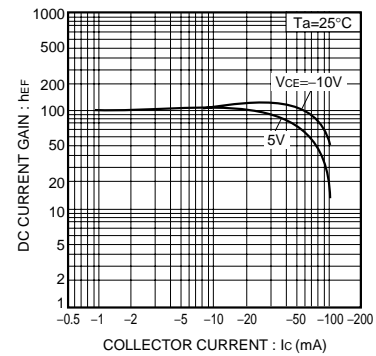


Fig.4 DC current gain vs.collector current ( I ) Fig.5 DC current gain vs.collector current ( II ) Fig.6 Collector-emitter saturation voltage vs. collector current

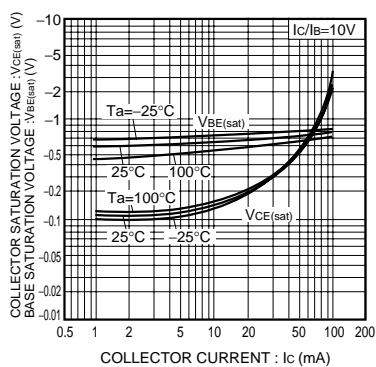


Fig.7 Collector-emitter saturation voltage vs. Collector current

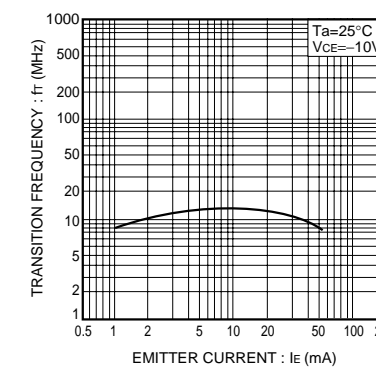


Fig.8 Gain bandwidth products vs. emitter current

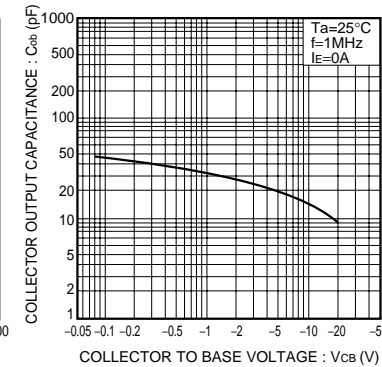


Fig.9 Collector output capacitance vs. collector-base voltage

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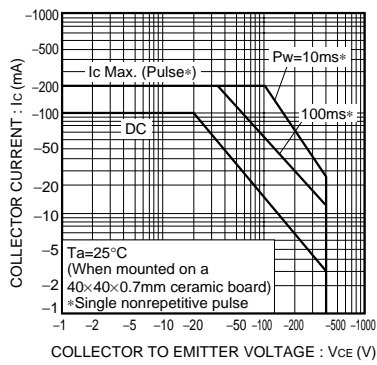


Fig.10 Safe operating area

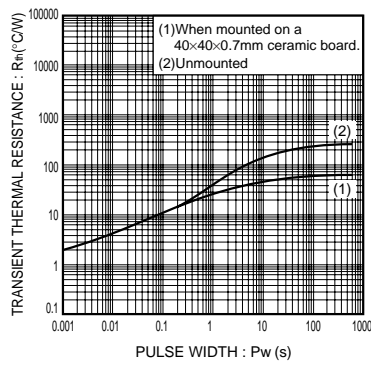


Fig.11 Transient thermal resistance

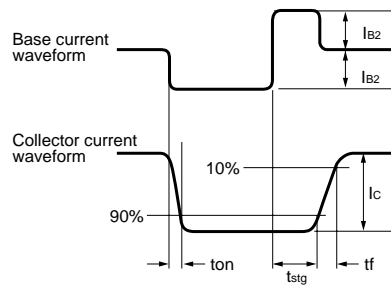
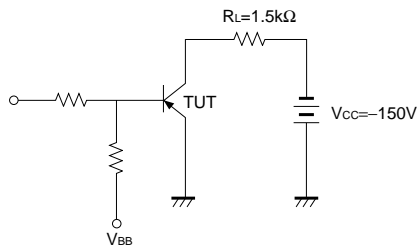


Fig.12 Switching characteristics measurement circuits

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